

# Table of Contents

Abstract.....	v
Zusammenfassung.....	vi
Acknowledgments.....	vii
Table of Contents.....	ix
List of Figures.....	xii
List of Tables.....	xv
List of Abbreviations.....	xvi
Chapter 1	
Introduction.....	1
Chapter 2	
Near-Field Scanning System.....	5
2.1 Near-Field Scanning Concepts.....	5
2.1.1 Classification of the Field Region.....	5
2.1.2 Measurement Region for Different Application.....	7
2.1.3 Near-Field Scanning Hardware.....	8
2.2 Key Parameters of the Near-Field Sensor.....	10
2.2.1 Spatial Resolution and Sensitivity.....	10
2.2.2 Scanning Time.....	10
2.2.3 Dynamic Range.....	11
2.3 State of the art.....	11
2.4 Conclusion.....	12
Chapter 3	
GaAs PHEMT and SiGe HBT Technologies.....	15
3.1 GaAs PHEMT Technology.....	15
3.1.1 Devices Available in ED02AH.....	18
3.1.2 PHEMT Modeling Considerations.....	19
3.2 SiGe HBT Technology.....	19
3.2.1 Devices Available in SG25.....	21
3.2.2 SiGe HBT Modeling Considerations.....	21
3.3 Technology Comparison.....	21
3.4 Conclusion.....	24
Chapter 4	
Loop and Dipole.....	25

4.1 Loop .....	25
4.1.1 Planar Loop in GaAs Technology .....	28
4.1.1.1 Electromagnetic Simulation and Frequency Independent Equivalent Circuit .....	28
4.1.1.2 Loop in Receiving Mode .....	30
4.1.1.3 Measurement of Planar Loop .....	31
4.1.2 Via-hole Loop in GaAs Technology .....	33
4.1.2.1 Via-hole Loop in Receiving Mode .....	33
4.1.2.2 Measurement of Via-hole Loop .....	34
4.2 Dipole .....	36
4.2.1 Dipole in GaAs Technology .....	37
4.2.1.1 Electromagnetic Simulation and Frequency Independent Equivalent Circuit .....	37
4.2.1.2 Dipole in Receiving Mode .....	38
4.2.1.3 Measurement of Planar Dipole .....	40
4.3 Planar Loop in SiGe Technology .....	42
4.3.1 EM Simulation and Frequency Independent Equivalent Circuit .....	43
4.3.2 Loop in Receiving Mode .....	44
4.3.3 Measurement of Loop in SiGe .....	45
4.4 Conclusion .....	46
Chapter 5	
Differential Amplifier .....	47
5.1 Differential Amplifiers in GaAs Technology .....	47
5.1.1 Common-Source Differential Amplifier .....	48
5.1.2 Common-Gate Differential Amplifier .....	52
5.1.3 Measurement of Designed Amplifiers .....	53
5.2 Switchable Double-Input Differential Amplifier .....	61
5.2.1 Switchable Common-Gate and Common-Source Amplifier .....	62
5.2.2 Switchable Common-Gate and Common-Gate Amplifier .....	65
5.3 Mixed-Mode Amplifiers .....	65
5.3.1 Mixed-Mode Representation .....	65
5.3.2 Mixed-Mode Amplifier in GaAs Technology .....	68
5.4 Differential Amplifier in SiGe Technology .....	74
5.5 Conclusion .....	77
Chapter 6	
Integrated Active Near-Field Sensor .....	79

6.1 Integrated Active Loop Sensor in GaAs Technology .....	79
6.1.1 Measurement with Integrated Excitation Loop.....	80
6.1.2 Measurement with Wire Loop Excitation.....	83
6.2 Integrated Active Dipole Sensor in GaAs Technology.....	85
6.3 Switchable Double-Output Sensor.....	88
6.4 Integrated Active Loop Sensor in SiGe Technology .....	90
6.4.1 Measurement with Integrated Excitation Loop.....	91
6.4.2 Measurement with Wire Loop Excitation.....	92
6.5 Conclusion .....	92
Chapter 7	
Conclusions.....	95
Appendix A	
Conductor Skin Effect: Ladder Equivalent Circuit.....	99
Appendix B	
Mixed-Mode S-parameters .....	102
Bibliography .....	105
Curriculum Vitae .....	113
List of Publications .....	114